



# **Sonic Fast Recovery Diode**

 $V_{RRM} = 1200 V$ 

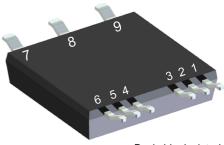
 $I_{DAV} = 60 A$ 

 $t_{rr} = 160 \, \text{ns}$ 

High Performance Fast Recovery Diode Low Loss and Soft Recovery 3~ Rectifier Bridge

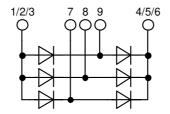
Part number

#### **DHG60U1200LB**



Backside: isolated





## Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

## **Applications:**

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

## Package: SMPD

- Isolation Voltage: 3000 V~
- Industry convenient outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

#### **Disclaimer Notice**

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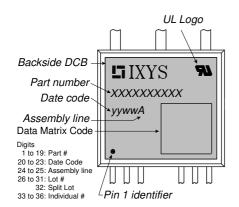


Fast Diode					Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
V <sub>RSM</sub>	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			1200	٧	
$V_{RRM}$	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			1200	V	
I <sub>R</sub>	reverse current, drain current	V <sub>R</sub> = 1200 V	$T_{VJ} = 25^{\circ}C$			50	μΑ	
		$V_R = 1200 V$	$T_{VJ} = 125^{\circ}C$			0.5	mΑ	
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 20 A	$T_{VJ} = 25^{\circ}C$			2.00	V	
		$I_F = 60 A$				2.92	V	
		I <sub>F</sub> = 20 A	T <sub>vJ</sub> = 125°C			1.94	V	
		$I_F = 60 A$				3.15	٧	
I DAV	bridge output current	T <sub>c</sub> = 80°C	T <sub>vJ</sub> = 150°C			60	Α	
		rectangular d = 1/₃					! ! !	
V <sub>F0</sub>	threshold voltage } for power loss calculation only		$T_{VJ} = 150$ °C			1.35	V	
$\mathbf{r}_{F}$	slope resistance				29	mΩ		
R <sub>thJC</sub>	thermal resistance junction to case					1.2	K/W	
R <sub>thCH</sub>	thermal resistance case to heatsink				0.40		K/W	
P <sub>tot</sub>	total power dissipation		$T_{\text{C}} = 25^{\circ}\text{C}$			100	W	
I <sub>FSM</sub>	max. forward surge current	$t = 10 \text{ ms}$ ; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			200	Α	
C¹	junction capacitance	$V_R = 600  \text{V}$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		11		pF	
I <sub>RM</sub>	max. reverse recovery current	<b>\</b>	$T_{VJ} = 25 ^{\circ}\text{C}$		19		Α	
		$I_F = 20 \text{ A}; V_R = 600 \text{ V}$	$T_{VJ} = 125$ °C		25		Α	
t <sub>rr</sub>	reverse recovery time	$\begin{cases} I_F = 20 \text{ A}; V_R = 600 \text{ V} \\ -\text{di}_F / \text{dt} = 600 \text{ A} / \mu \text{s} \end{cases}$	$T_{VJ} = 25 ^{\circ}\text{C}$		160		ns	
		)	$T_{VJ} = 125$ °C		280		ns	





Package SMPD				ı	Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
I <sub>RMS</sub>	RMS current	per terminal				100	Α	
T <sub>VJ</sub>	virtual junction temperature			-55		150	°C	
T <sub>op</sub>	operation temperature			-55		125	°C	
T <sub>stg</sub>	storage temperature			-55		150	°C	
Weight					8.5		g	
F <sub>c</sub>	mounting force with clip			40		130	N	
d <sub>Spp/App</sub>	creepage distance on surface   striking distance through air		terminal to terminal	1.6			mm	
d <sub>Spb/Apb</sub>			terminal to backside	4.0			mm	
V <sub>ISOL</sub>	isolation voltage	t = 1 second		3000			٧	
	t = 1 minute	50/60 Hz, RMS; IISOL ≤ 1 mA	2500			٧		



## Part description

D = Diode

H = Sonic Fast Recovery Diode

G = extreme fast

60 = Current Rating [A]

U = 3~ Rectifier Bridge 1200 = Reverse Voltage [V]

LB = SMPD-B

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DHG60U1200LB-TUB	DHG60U1200LB-TUB	Tube	20	524936
Alternative	DHG60U1200LB-TRR	DHG60U1200LB	Tape & Reel	200	524950

<b>Equivalent Circuits for Simulation</b>			* on die level	$T_{VJ} = 150 ^{\circ}\text{C}$
$I \rightarrow V_0$	)—[R <sub>0</sub> ]-	Fast Diode		
V <sub>0 max</sub>	threshold voltage	1.35		V
$R_{0  max}$	slope resistance *	27		$m\Omega$



## **Outlines SMPD**

